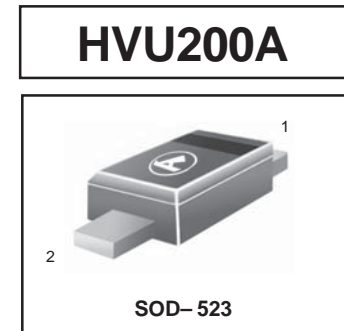


Variable Capacitance Diode for Electronic Tuning

FEATURES

- High capacitance ratio(n = 10min) and suitable for wide band tuner.
- Ultra small Resin Package (URP) is suitable for surface mount design.
- Low series resistance and good C-V linearity.



DEVICE MARKING

HVU200A = 2

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

Item	Symbol	Value	Unit
Reverse voltage	V _R	32	V
Junction temperature	T _j	125	°C
Storage temperature	T _{stg}	- 55 to +125	°C

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse current	I _{R1}	-	-	10	nA	V _R = 30V
	I _{R2}	-	-	100		V _R = 30V, T _A = 60°C
Capacitance	C ₂	27.7	-	31.8	pF	V _R = 2V, f = 1 MHz
	C ₂₅	2.67	-	3.03		V _R = 25V, f = 1 MHz
Capacitance ratio	n	10.0	-	-	-	C ₂ / C ₂₅
Series resistance	r _s	-	-	0.70	Ω	V _R = 5V, f = 470 MHz
Matching error	ΔC/C*1	-	-	2.0	%	V _R = 2 to 25V, f = 1 MHz

Note: *1. C.C system (Continuous Connected taping system) enable to make any 10 pcs of ΔC/C continuous in a reel , expect extension to another group.

Calculate Matching Error,

$$\Delta C/C = \frac{(C_{\max} - C_{\min})}{C_{\min}} \times 100 (\%)$$

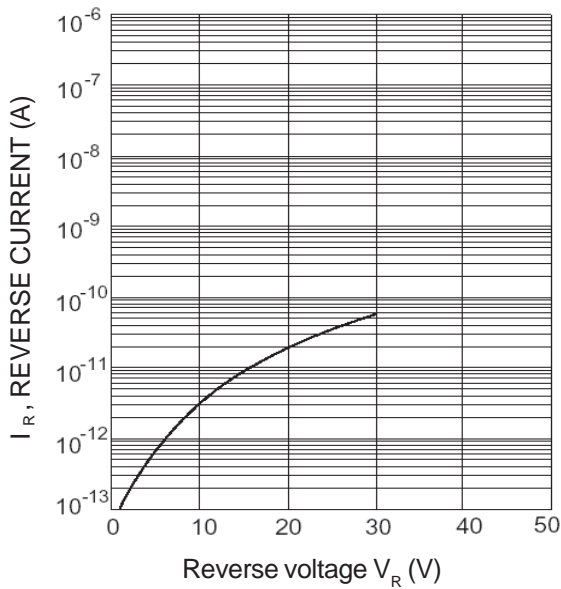
HVU200A


Fig.1 Reverse current Vs. Reverse voltage

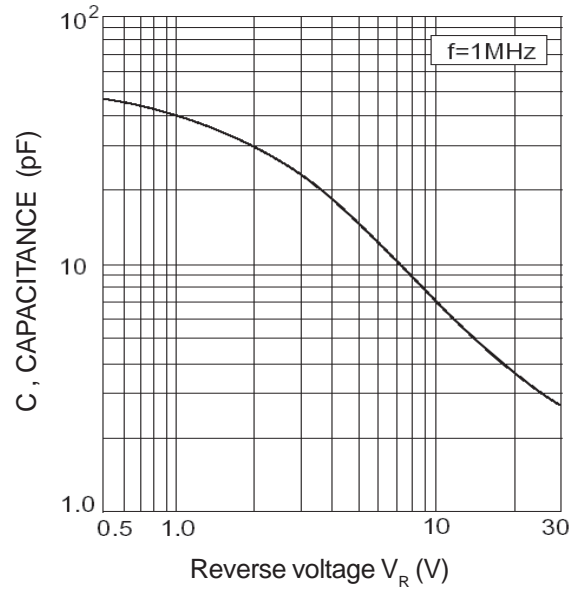


Fig.2 Capacitance Vs. Reverse voltage

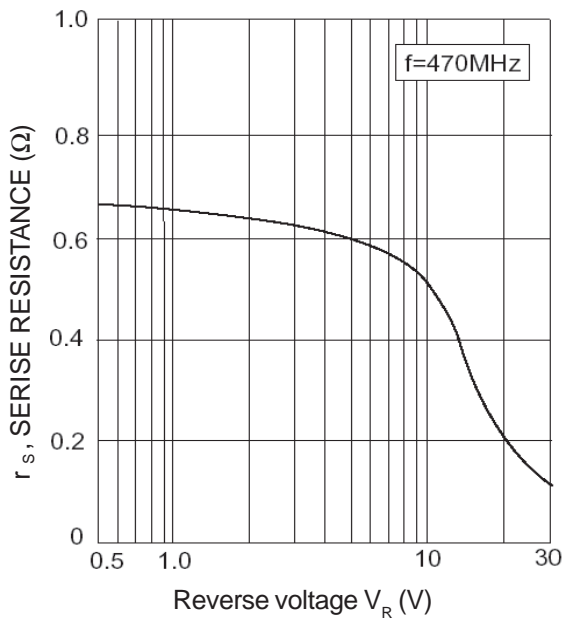


Fig.3 Series resistance Vs. Reverse voltage

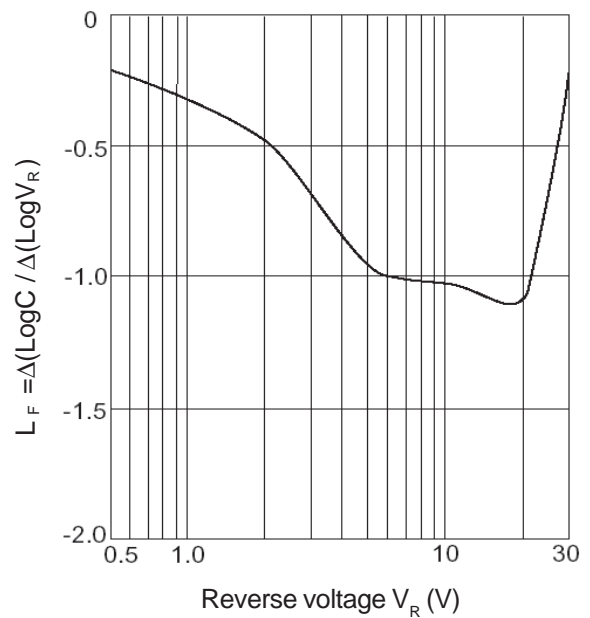


Fig.4 Linearity factor Vs. Reverse voltage